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TinyLogic ULP-A 2-Input Exclusive-OR Gate

NC7SV86

The NC7SV86 is a single 2–Input Exclusive–OR Gate in tiny footprint packages. The device is designed to operate for $V_{CC} = 0.9$ V to 3.6 V.

Features

- Designed for 0.9 V to 3.6 V V_{CC} Operation
- 1.7 ns t_{PD} at 3.3 V (Typ)
- Inputs/Outputs Over–Voltage Tolerant up to 3.6 V
- I_{OFF} Supports Partial Power Down Protection
- Source/Sink 24 mA at 3.3 V
- Available in SC−88A and MicroPak[™] Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

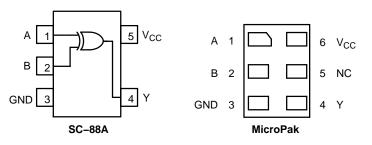
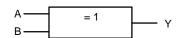


Figure 1. Pinout Diagrams (Top Views)





PIN ASSIGNMENT

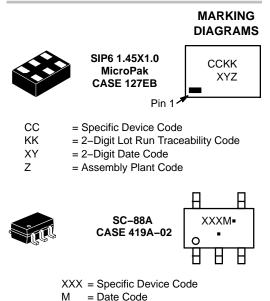
Pin	SC88A	MicroPak
1	А	А
2	В	В
3	GND	GND
4	Y	Y
5	V _{CC}	N.C.
6	_	V _{CC}

N.C. = No Connect

ON

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= Pb-Free Package

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 6 of this data sheet.

FUNCTION TABLE

Inp	Output	
A	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

MAXIMUM RATINGS

Symbol	Characteris	tics	Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +4.3	V
V _{IN}	DC Input Voltage		-0.5 to +4.3	V
V _{OUT}	DC Output Voltage	Active–Mode (High or Low State) Tri–State Mode (Note 1) Power–Down Mode (V _{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +4.3 -0.5 to +4.3	V
I _{IK}	DC Input Diode Current	V _{IN} < GND	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < GND	-50	mA
I _{OUT}	DC Output Source/Sink Current		±50	mA
I _{CC} or I _{GND}	DC Supply Current per Supply Pin or Ground	d Pin	±50	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 S	Seconds	260	°C
TJ	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 2)	SC–88A MicroPak	377 154	°C/W
PD	Power Dissipation in Still Air	SC–88A MicroPak	332 812	mW
MSL	Moisture Sensitivity		Level 1	-
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in	-
V_{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
I _{Latchup}	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
Applicable to devices with outputs that may be tri-stated.
Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow per JESD51-7.
HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A

(Machine Model) be discontinued.

4. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Max	Unit
V _{CC}	Positive DC Supply Voltage		0.9	3.6	V
V _{IN}	DC Input Voltage		0	3.6	V
V _{OUT}	DC Output Voltage	Active–Mode (High or Low State) Tri–State Mode (Note 1) Power–Down Mode (V _{CC} = 0 V)	0 0 0	V _{CC} 3.6 3.6	
T _A	Operating Temperature Range		-40	+85	°C
t _r , t _f	Input Transition Rise and Fall Time	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

				Т	A = 25°	с	T _A = -40°C	C to +85°C		
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Мах	Unit	
VIH	High-Level Input		0.9	_	0.5	-	_	-	V	
	Voltage		1.1 to 1.3	0.65 x V _{CC}	_	-	0.65 x V _{CC}	-	1	
			1.4 to 1.6	0.65 x V _{CC}	_	-	0.65 x V _{CC}	-	1	
			1.65 to 1.95	$0.65 \times V_{CC}$	-	-	0.65 x V _{CC}	-	1	
			2.3 to <2.7	1.6	-	-	1.6	-	1	
			2.7 to 3.6	2.0	-	_	2.0	_	1	
V _{IL}	Low-Level Input		0.9	-	0.5	-	-	-	V	
	Voltage		1.1 to 1.3	-	-	$0.35 \times V_{CC}$	-	0.35 x V _{CC}	1	
			1.4 to 1.6	-	-	$0.35 \times V_{CC}$	-	0.35 x V _{CC}	1	
			1.65 to 1.95	-	-	$0.35 \times V_{CC}$	-	0.35 x V _{CC}	1	
				2.3 to <2.7	-	-	0.7	-	0.7	1
			2.7 to 3.6	-	-	0.8	_	0.8	1	
V _{OH}	High-Level Output	$V_{IN} = V_{IH} \text{ or } V_{IL}$							V	
	Voltage	I _{OH} = -100 μA	0.9	-	V _{CC} - 0.1	-	_	_		
			1.1 to 1.3	V _{CC} – 0.1	-	-	V _{CC} – 0.1	-		
			1.4 to 1.6	V _{CC} – 0.1	-	-	V _{CC} – 0.1	-		
			1.65 to 1.95	V _{CC} – 0.2	-	-	V _{CC} - 0.2	-		
			2.3 to <2.7	V _{CC} – 0.2	-	-	$V_{CC} - 0.2$	-		
			2.7 to 3.6	V _{CC} – 0.2	-	-	V _{CC} - 0.2	-		
		$I_{OH} = -2 \text{ mA}$	1.1 o 1.3	0.75 x V _{CC}	-	-	0.75 x V _{CC}	-		
		$I_{OH} = -4 \text{ mA}$	1.4 to 1.6	$0.75 ext{ x V}_{CC}$	-	-	$0.75 \times V_{CC}$	-		
		$I_{OH} = -6 \text{ mA}$	1.65 to 1.95	1.25	-	-	1.25	-		
			2.3 to <2.7	2.0	-	-	2.0	-		
		I _{OH} = -12 mA	2.3 to <2.7	1.8	-	-	1.8	-		
			2.7 to 3.6	2.2	-	-	2.2	-		
		I _{OH} = -18 mA	2.3 to <2.7	1.7	-	-	1.7	-]	
			2.7 to 3.6	2.4	-	-	2.4	-		
		I _{OH} = -24 mA	2.7 to 3.6	2.2	-	-	2.2	-		

DC ELECTRICAL CHARACTERISTICS (continued)

				٦	T _A = 25°C			T _A = -40°C to +85°C	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
V _{OL}	Low-Level	$V_{IN} = V_{IH} \text{ or } V_{IL}$							V
	Output Voltage	I _{OL} = 100 μA	0.9	-	0.1	-	-	-	
			1.1 to 1.3	-	-	0.1	-	0.1	
			1.4 to 1.6	-	-	0.1	-	0.1	
			1.65 to 1.95	-	-	0.2	-	0.2	
			2.3 to < 2.7	-	-	0.2	-	0.2	
			2.7 to 3.6	-	-	0.2	-	0.2	
		$I_{OL} = 2 \text{ mA}$	1.1 o 1.3	-	-	$0.25 \times V_{CC}$	-	$0.25 \times V_{CC}$	
		I _{OL} = 4 mA	1.4 to 1.6	-	-	$0.25 \times V_{CC}$	-	$0.25 \mathrm{~x~V_{CC}}$	
		I _{OL} = 6 mA	1.65 to 1.95	-	-	0.3	-	0.3	
		I _{OL} = 12 mA	2.3 to <2.7	-	-	0.4	-	0.4	
			2.7 to 3.6	-	-	0.4	-	0.4	
		I _{OL} = 18 mA	2.3 to <2.7	-	-	0.6	-	0.6	
			2.7 to 3.6	-	-	0.4	-	0.4	
		I _{OL} = 24 mA	2.7 to 3.6	-	-	0.55	-	0.55	
I _{IN}	Input Leakage Current	$V_{IN} = 0 V \text{ to } 3.6 V$	0.9 to 3.6	-	-	±0.1	-	±0.5	μΑ
I _{OFF}	Power Off Leakage Current		0	_	-	0.5	-	0.5	μΑ
Icc	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	0.9 to 3.6	_	-	0.9	_	0.9	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

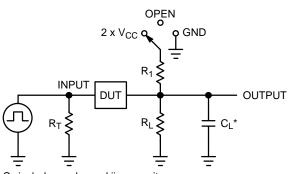
AC ELECTRICAL CHARACTERISTICS

				Т	「 _A = 25°0)	T _A = -40°C	C to +85°C	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
t _{PLH} ,	Propagation Delay,	R_L = 1 MΩ, C_L = 15 pF	0.9	-	17.7	-	-	-	ns
t _{PHL}	(A or B) to Y (Figures 3 and 4)	$R_L = 2 \text{ k}\Omega, C_L = 15 \text{ pF}$	1.1 to 1.3	-	6.0	15.0	-	18.6	
			1.4 to 1.6	-	3.6	8.7	-	9.7	
		$R_L = 500 \ \Omega$, $C_L = 30 \ pF$	1.65 to 1.95	-	2.9	6.0	-	6.8	
			2.3 to 2.7	-	2.0	3.6	-	4.7	
			2.7 to 3.6	-	1.7	3.3	_	4.0	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition	Typical (T _A = 25°C)	Unit
C _{IN}	Input Capacitance	$V_{CC} = 0 V$	2.0	pF
C _{OUT}	Output Capacitance	$V_{CC} = 0 V$	4.5	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	f = 10 MHz, V_{CC} = 0.9 to 3.6 V, V _{IN} = 0 V or V _{CC}	8.0	pF

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no–load dynamic power consumption: $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.



90%

V_{mi}

Test	Switch Position			
t _{PLH} / t _{PHL}	Open			
t _{PLZ} / t _{PZL}	2 x V _{CC}			
t _{PHZ} / t _{PZH}	GND			

 C_L includes probe and jig capacitance R_T is Z_{OUT} of pulse generator (typically 50 $\Omega)$ f = 1 MHz

90%

 V_{mo}

 V_{mo}

V_{mi}

♦ t_{PLH}

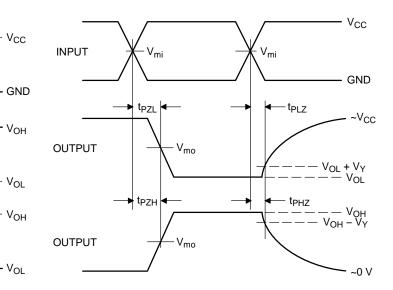
t_r = 3 ns -

10%

INPUT

OUTPUT

OUTPUT



Eiguro	2	Toct	Circuit
rigure	J.	rest	Circuit

- t_f = 3 ns

 V_{mo}

 V_{mo}

10%

|t_{PLH}|◀

+ t_{PHL}

V _{CC} , V	V _{mi} , V	V _{mo} , V	V _Y , V
0.9	V _{CC} / 2	V _{CC} / 2	0.1
1.1 to 1.3	V _{CC} / 2	V _{CC} / 2	0.1
1.4 to 1.6	V _{CC} / 2	V _{CC} / 2	0.1
1.65 to 1.95	V _{CC} / 2	V _{CC} / 2	0.15
2.3 to 2.7	V _{CC} / 2	V _{CC} / 2	0.15
3.0 to 3.6	1.5	1.5	0.3

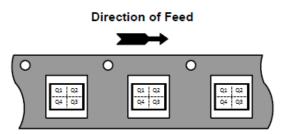
Figure 4. Switching Waveforms

ORDERING INFORMATION

Device	Package	Marking	Pin 1 Orientation (See below)	Shipping [†]
NC7SV86P5X	SC-88A	V86	Q4	3000 / Tape & Reel
NC7SV86L6X	MicroPak	H5	Q4	5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

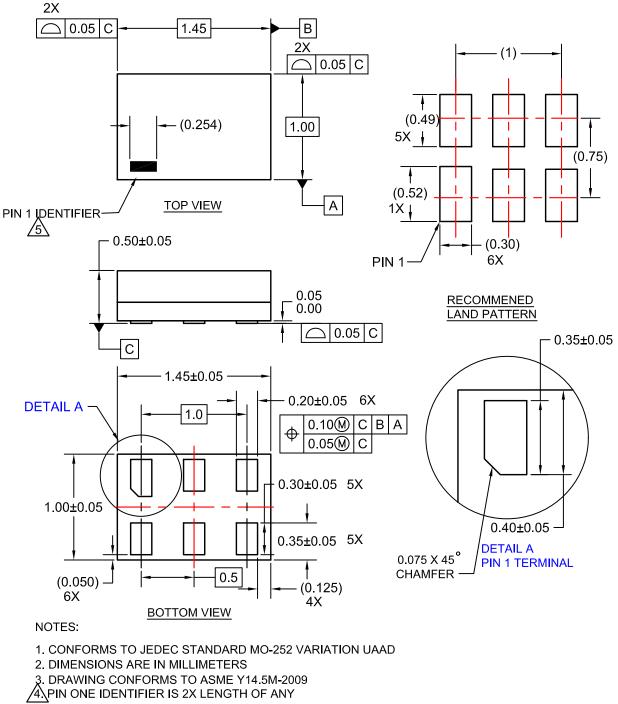
Pin 1 Orientation in Tape and Reel



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PACKAGE DIMENSIONS

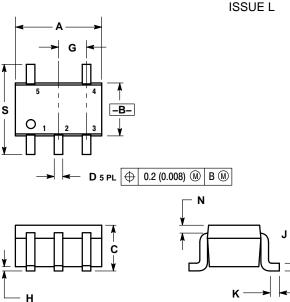
SIP6 1.45X1.0 CASE 127EB ISSUE O



OTHER LINE IN THE MARK CODE LAYOUT.

PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE I



NOTES:

1. DIMENSIONING AND TOLERANCING

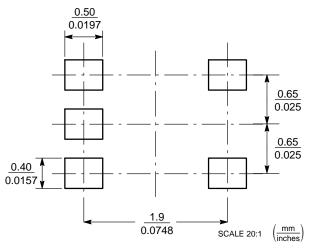
PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

 419A–01 OBSOLETE. NEW STANDARD 419A–02.

 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
Ν	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

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